

Discrete IGBTs Silicon N-Channel IGBT

GT50N324

1. Applications

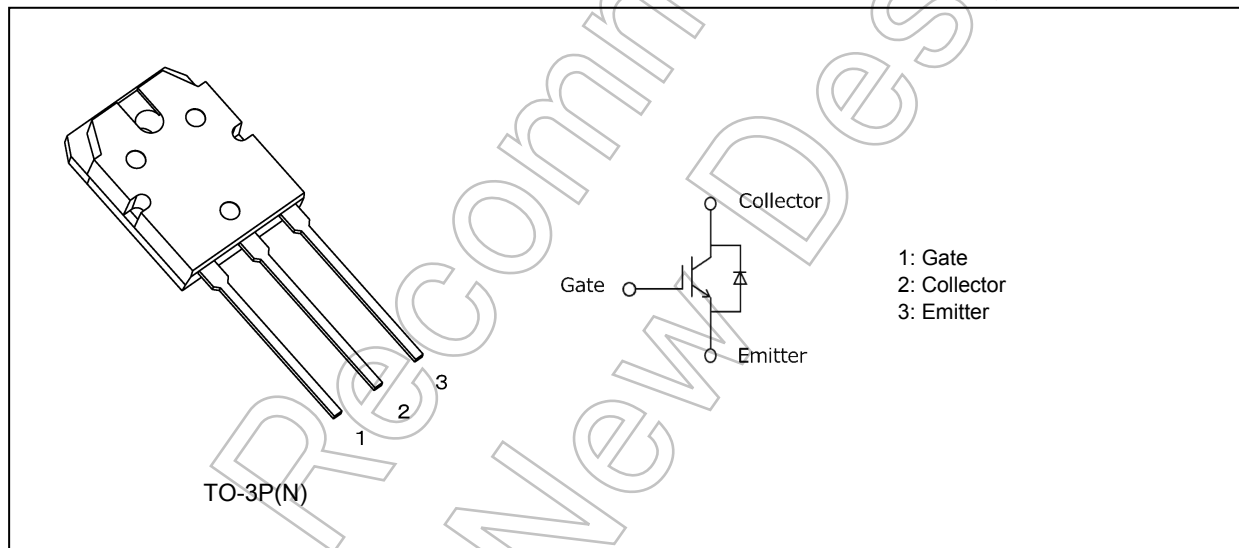
- Dedicated to Voltage-Resonant Inverter Switching Applications

Note: The product(s) described herein should not be used for any other application.

2. Features

- (1) Sixth generation
- (2) Enhancement mode
- (3) High-speed switching:
 IGBT $t_f = 0.11 \mu\text{s}$ (typ.) ($I_C = 60 \text{ A}$)
 FRD $t_{rr} = 0.8 \mu\text{s}$ (typ.) ($di/dt = -20 \text{ A}/\mu\text{s}$)
- (4) Low saturation voltage: $V_{CE(sat)} = 1.9 \text{ V}$ (typ.) ($I_C = 60 \text{ A}$)
- (5) FRD included between emitter and collector

3. Packaging and Internal Circuit



Start of commercial production

2008-03

4. Absolute Maximum Ratings (Note) ($T_a = 25\text{ }^\circ\text{C}$, unless otherwise specified)

| Characteristics | Symbol | Rating | Unit |
|---------------------------------------------------------------------|-----------|------------|------------------|
| Collector-emitter voltage | V_{CES} | 1000 | V |
| Gate-emitter voltage | V_{GES} | ± 25 | V |
| Collector current (DC) | I_C | 50 | A |
| Collector current (1 ms) | I_{CP} | 120 | A |
| Diode forward current (DC) | I_F | 15 | A |
| Diode forward current (1 ms) | I_{FP} | 120 | A |
| Collector power dissipation ($T_c = 25\text{ }^\circ\text{C}$) | P_C | 150 | W |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | -55 to 150 | $^\circ\text{C}$ |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

In general, loss of IGBT increases more when it has positive temperature coefficient and gets higher temperature.

In case that the temperature rise due to loss of IGBT exceeds the heat release capacity of a device, it leads to thermorunaway and results in destruction.

Therefore, please design heat release of a device with due consideration to the temperature rise of IGBT.

5. Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---------------------------------------------|---------------|------|---------------------------|
| Junction-to-case thermal resistance (IGBT) | $R_{th(j-c)}$ | 0.83 | $^\circ\text{C}/\text{W}$ |
| Junction-to-case thermal resistance (diode) | | 4.0 | |

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25\text{ }^\circ\text{C}$, unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------------|---------------|-------------------------------------------------|-----|------|-----------|------|
| Gate leakage current | I_{GES} | $V_{GE} = \pm 25\text{ V}, V_{CE} = 0\text{ V}$ | — | — | ± 500 | nA |
| Collector cut-off current | I_{CES} | $V_{CE} = 1000\text{ V}, V_{GE} = 0\text{ V}$ | — | — | 1 | mA |
| Gate-emitter cut-off voltage | $V_{GE(OFF)}$ | $I_C = 60\text{ mA}, V_{CE} = 5\text{ V}$ | 3.0 | — | 6.0 | V |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 60\text{ A}, V_{GE} = 15\text{ V}$ | — | 1.9 | 2.5 | V |
| Diode forward voltage | V_F | $I_F = 15\text{ A}, V_{GE} = 0\text{ V}$ | — | 1.2 | 1.9 | V |

6.2. Dynamic Characteristics ($T_a = 25\text{ }^\circ\text{C}$, unless otherwise specified)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|--------------------------------|-----------|------------------------------------------------------------------------------------------------------------------------------------|-----|------|------|---------------|
| Input capacitance | C_{ies} | $V_{CE} = 10\text{ V}, V_{GE} = 0\text{ V}, f = 1\text{ MHz}$ | — | 5500 | — | pF |
| Switching time (rise time) | t_r | Resistive load $V_{CE} = 600\text{ V}, I_C = 60\text{ A}, V_{GE} = \pm 15\text{ V}, R_G = 51\ \Omega$ See Fig. 6.2.1, 6.2.2. | — | 0.23 | — | μs |
| Switching time (turn-on time) | t_{on} | | — | 0.33 | — | |
| Switching time (fall time) | t_f | | — | 0.11 | 0.25 | |
| Switching time (turn-off time) | t_{off} | | — | 0.70 | — | |
| Reverse recovery time | t_{rr} | $I_F = 15\text{ A}, V_{GE} = 0\text{ V}, di/dt = -20\text{ A}/\mu\text{s}$ | — | 0.8 | — | μs |

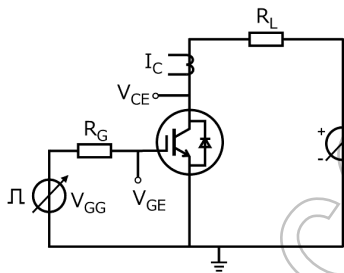


Fig. 6.2.1 Test Circuit of Switching Time

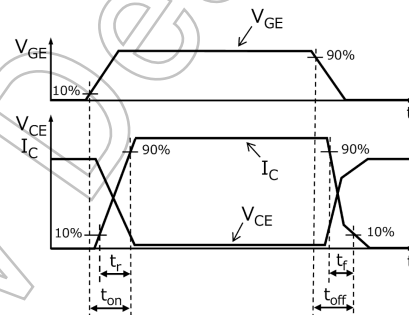
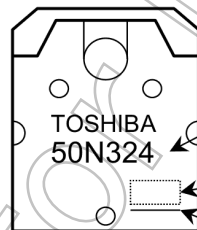


Fig. 6.2.2 Timing Chart of Switching Time

7. Marking (Note)



Part No.
(or abbreviation code)

Lot No.

Note

Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

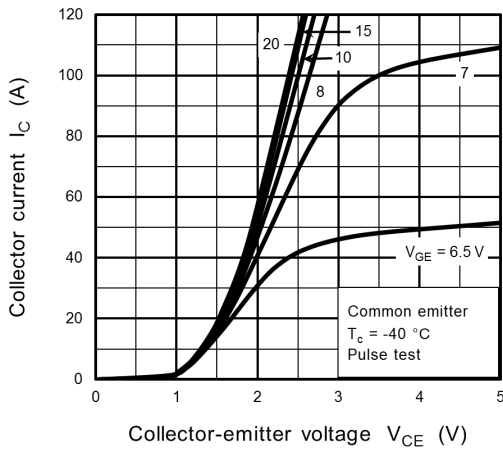


Fig. 8.1 $I_C - V_{CE}$

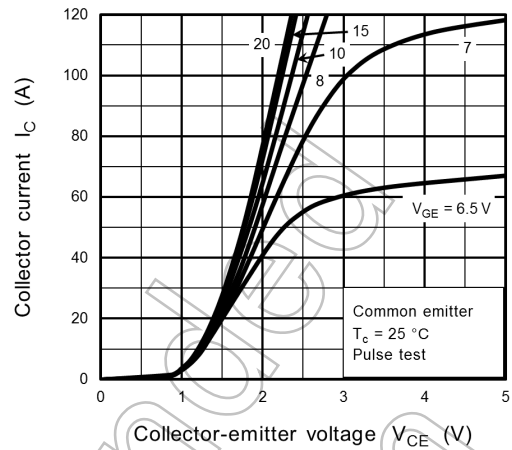


Fig. 8.2 $I_C - V_{CE}$

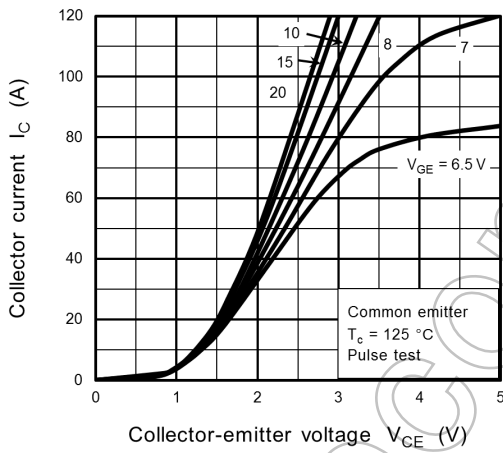


Fig. 8.3 $I_C - V_{CE}$

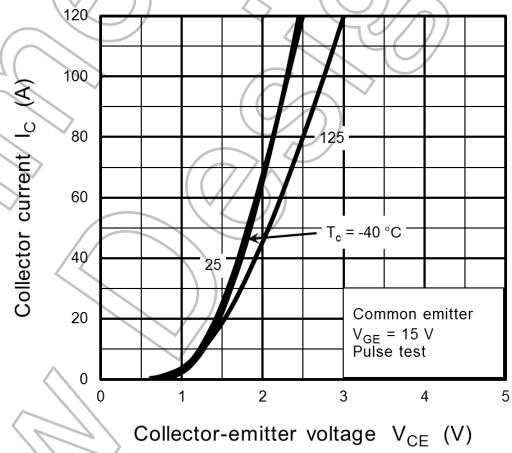


Fig. 8.4 $I_C - V_{CE}$

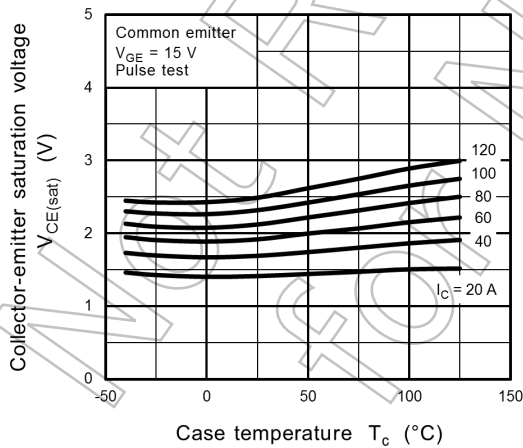


Fig. 8.5 $V_{CE(sat)} - T_c$

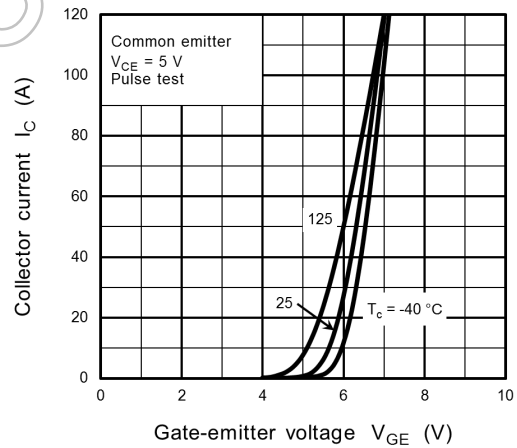


Fig. 8.6 $I_C - V_{GE}$

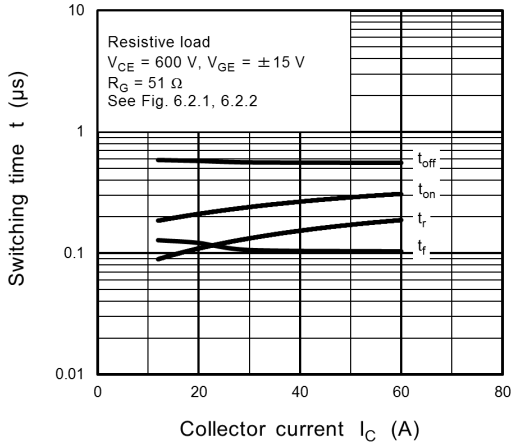


Fig. 8.7 Switching Time - I_C

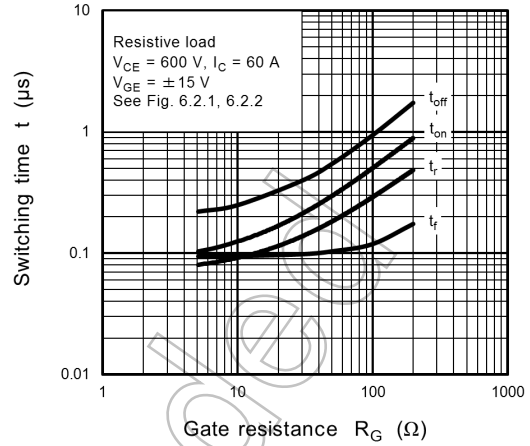


Fig. 8.8 Switching Time - R_G

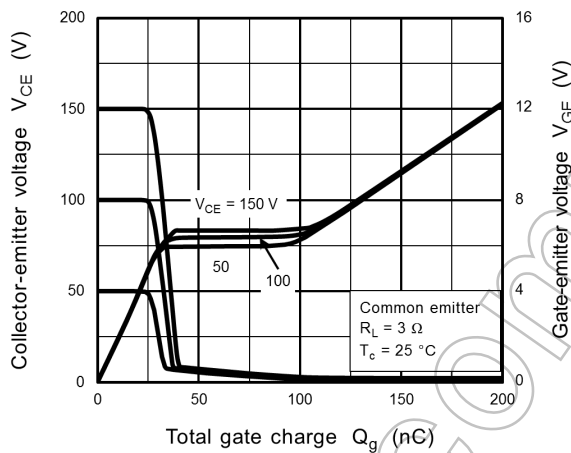


Fig. 8.9 V_{CE} , V_{GE} - Q_g

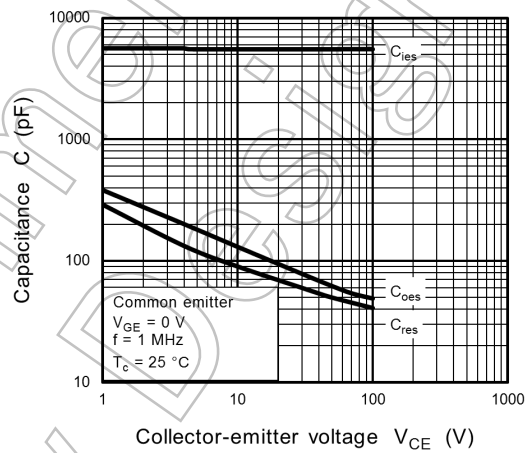


Fig. 8.10 C - V_{CE}

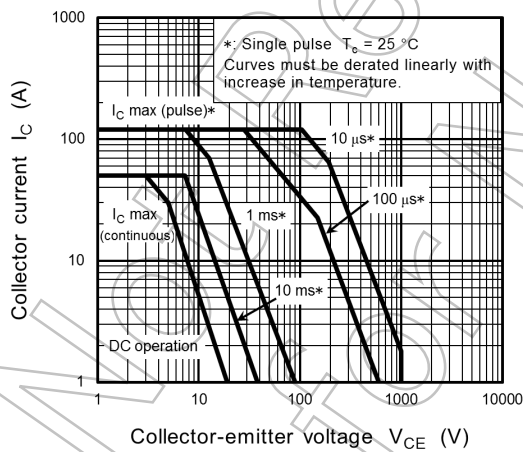


Fig. 8.11 Safe Operating Area (Guaranteed Maximum)

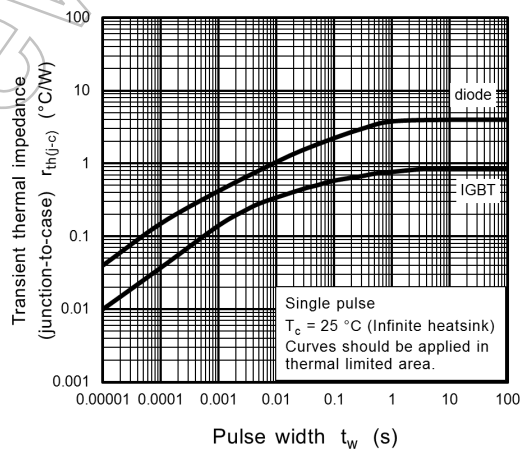


Fig. 8.12 $r_{th(j-c)}$ - t_w (Guaranteed Maximum)

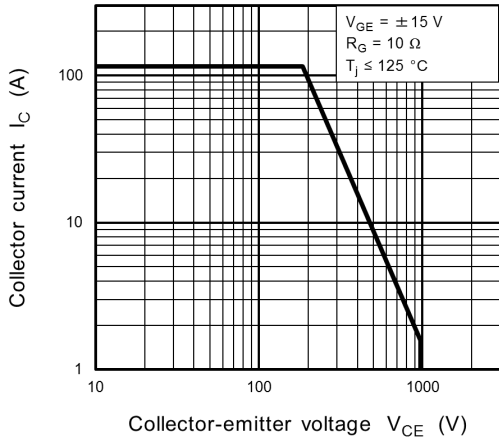


Fig. 8.13 Reverse Bias SOA (Guaranteed Maximum)

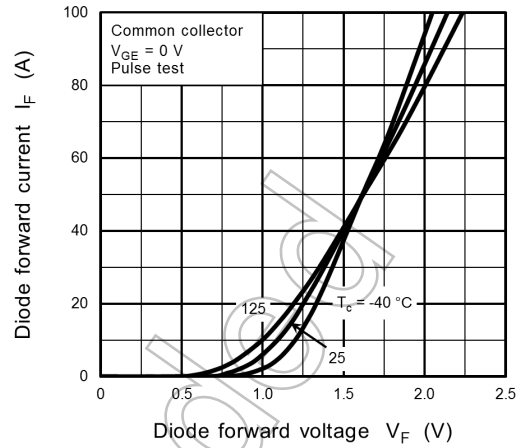


Fig. 8.14 $I_F - V_F$

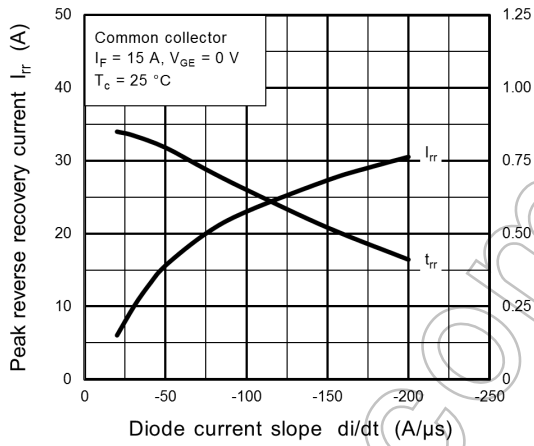


Fig. 8.15 $I_{rr}, t_{rr} - di/dt$

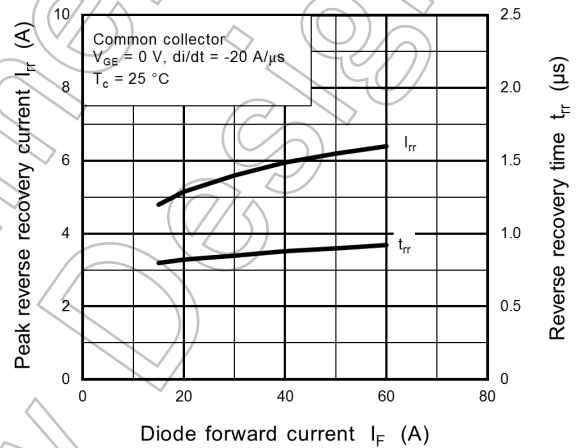
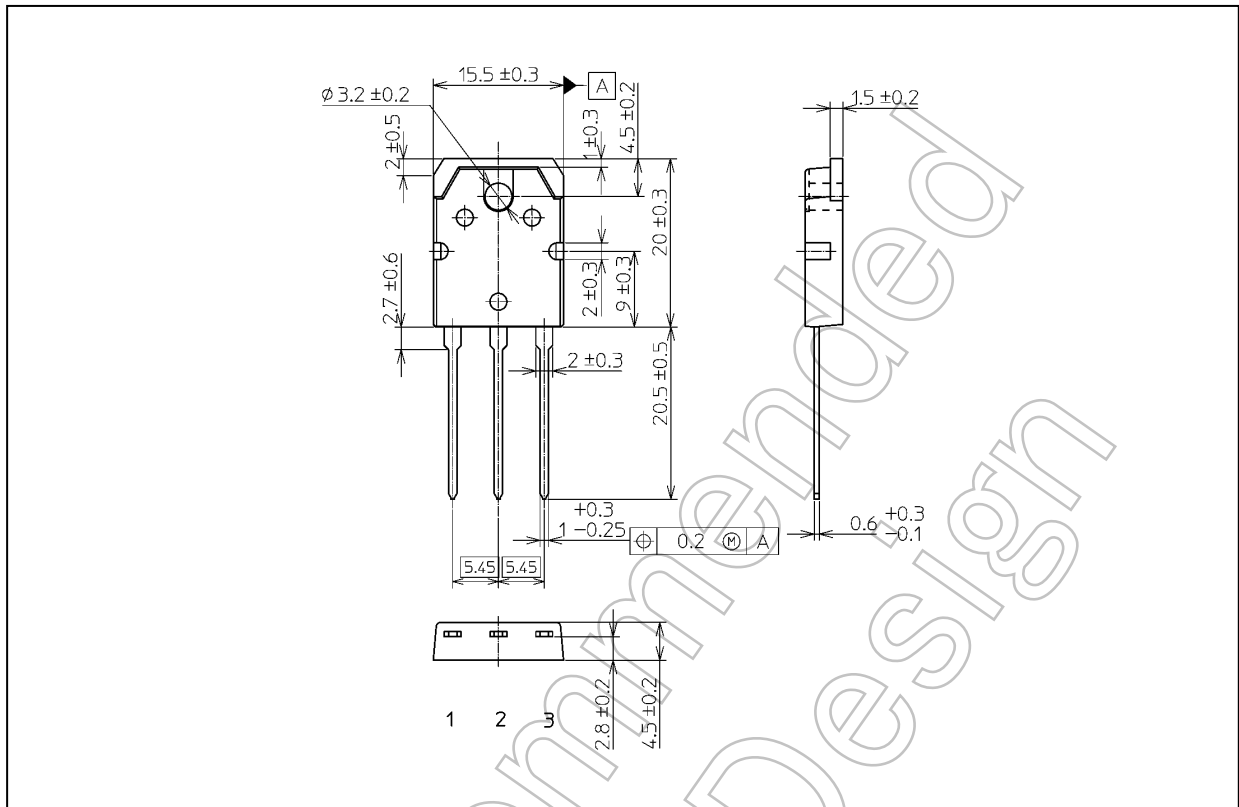


Fig. 8.16 $I_{rr}, t_{rr} - I_F$

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 4.6 g (typ.)

| Package Name(s) |
|--------------------|
| TOSHIBA: 2-16C1S |
| Nickname: TO-3P(N) |

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